

TLP293-4

**Programmable Controllers
Switching Power Supplies
Simplex/Multiplex Data Transmissions**

TLP293-4 consists of phototransistors optically coupled to infrared emitting diodes.

TLP293-4 photocoupler is housed in the very small and thin SO16 package. Since the TLP293-4 is guaranteed wide operating temperature range (Ta= -55 to 125 °C), and high isolation voltage (3750 Vrms), it is suitable for high-density surface mount applications such as programmable controllers.

- Collector-Emitter Voltage : 80 V (min)
- Current Transfer Ratio : 50% (min)
GB rank: 100% (min)
- Isolation Voltage : 3750 Vrms (min)
- Operation temperature range: -55 to 125 °C
- Safety standards
UL-recognized: UL 1577, File No.E67349
cUL-recognized: CSA Component Acceptance Service No.5A
File No.E67349
CQC- approved : GB4943.1, GB8898 Thailand Factory



仅适用于海拔 2000 m 以下地区安全使用

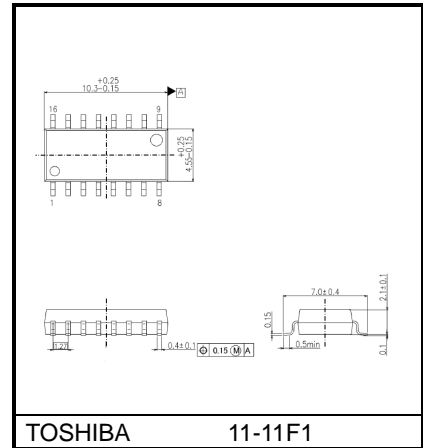
VDE-approved : EN 60747-5-5, EN 62368-1 (Note1)

Note : When a VDE approved type is needed, please designate the Option (V4).

Construction Mechanical Rating

Creepage Distance	5.0 mm (min)
Clearance	5.0 mm (min)
Internal isolation thickness	0.4 mm (min)

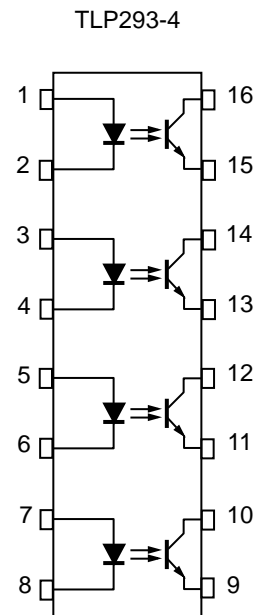
Unit: mm



TOSHIBA 11-11F1

Weight: 0.19 g (typ.)

Pin Configuration



- 1,3,5,7 : Anode
- 2,4,6,8 : Cathode
- 9,11,13,15 : Emitter
- 10,12,14,16 : Collector

Start of commercial production
2014-04

Current Transfer Ratio (Unless otherwise specified, Ta=25°C)

Rank (Note 1)	Test condition	Current Transfer Ratio (%)		Marking of Classification
		I _C / I _F		
		Min	Max	
Blank	I _F = 5 mA, V _{CE} = 5 V	50	600	Blank
GB		100	600	GB
LA (Note2)	I _F = 0.5 mA, V _{CE} = 5 V	50	600	LA
LGB (Note2)		100	600	LB

Note1: Specify both the part number and a rank in this format when ordering.

Example: rank GB: TLP293-4(GB,E)

For safety standard certification, however, specify the part number alone.

TLP293-4 (GB,E: TLP293-4

Note2: The LA and LGB rank are made CTR rank of the low input current condition.

Absolute Maximum Ratings (Note)(Unless otherwise specified, Ta = 25°C)

Characteristics		Symbol	Note	Rating	Unit
LED	Input forward current	I _F		50	mA
	Input forward current derating (Ta≥50°C)	ΔI _F / ΔTa		-0.59	mA / °C
	Input forward current(Pulsed)	I _{FP}	(Note 1)	1	A
	Power dissipation	P _D		70	mW
	Power dissipation derating(Ta≥50°C)	ΔP _D / ΔTa		-0.82	mW / °C
	Input reverse voltage	V _R		5	V
	Junction temperature	T _j		125	°C
DETECTOR	Collector-emitter voltage	V _{CEO}		80	V
	Emitter-collector voltage	V _{ECO}		7	V
	Collector current	I _C		50	mA
	Collector power dissipation (1 Circuit)	P _C		100	mW
	Collector power dissipation derating(Ta≥25°C) (1 Circuit)	ΔP _C / ΔTa		-0.91	mW / °C
	Junction temperature	T _j		125	°C
COMMON	Operating temperature range	T _{opr}		-55 to 125	°C
	Storage temperature range	T _{stg}		-55 to 125	°C
	Lead soldering temperature	T _{sol}		260 (10 s)	°C
	Total power dissipation (1 Circuit)	P _T		170	mW
	Input power dissipation derating(Ta≥25°C) (1 Circuit)	ΔP _T / ΔTa		-1.55	mW / °C
	Isolation Voltage AC, 60 s, R.H.≤60 %	BV _S	(Note 2)	3750	V _{rms}

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note1: Pulse width ≤ 100 μs, frequency 100 Hz

Note2: This device is considered as a two-terminal device: All pins on the LED side are shorted together, and all pin on the photodetector side are shorted together.

Electrical Characteristics (Unless otherwise specified, Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
LED	Input forward voltage	V _F	I _F = 10 mA	1.1	1.25	1.4	V
	Input reverse current	I _R	V _R = 5 V	—	—	10	μA
	Input capacitance	C _T	V = 0 V, f = 1 MHz	—	30	—	pF
DETECTOR	Collector-emitter breakdown voltage	V _{(BR) CEO}	I _C = 0.5 mA	80	—	—	V
	Emitter-collector breakdown voltage	V _{(BR) ECO}	I _E = 0.1 mA	7	—	—	V
	Dark current	I _{DARK}	V _{CE} = 48 V,	—	0.01	0.08	μA
			V _{CE} = 48 V, Ta = 85 °C	—	2	50	μA
Collector-emitter capacitance	C _{CE}	V = 0 V, f = 1 MHz	—	10	—	pF	

Coupled Electrical Characteristics (Unless otherwise specified, Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Current transfer ratio	I _C / I _F	I _F = 5 mA, V _{CE} = 5 V Rank GB	50	—	600	%
			100	—	600	
Saturated current transfer ratio	I _C / I _F (sat)	I _F = 1 mA, V _{CE} = 0.4 V Rank GB	—	60	—	%
			30	—	—	
Collector-emitter saturation voltage	V _{CE} (sat)	I _C = 2.4 mA, I _F = 8 mA	—	—	0.3	V
		I _C = 0.2 mA, I _F = 1 mA Rank GB	—	0.2	—	
			—	—	0.3	
Off-state collector current	I _C (off)	V _F = 0.7 V, V _{CE} = 48 V	—	—	10	μA

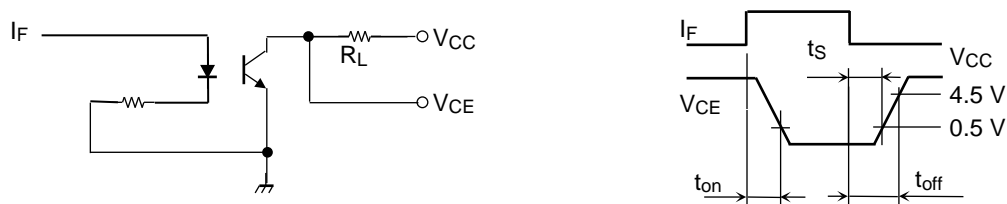
Isolation Characteristics (Unless otherwise specified, Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total capacitance (input to output)	C _S	V _S = 0 V, f = 1 MHz	—	0.8	—	pF
Isolation resistance	R _S	V _S = 500 V, R.H. ≤ 60 %	1 × 10 ¹²	10 ¹⁴	—	Ω
Isolation voltage	BV _S	AC, 60 s	3750	—	—	V _{rms}

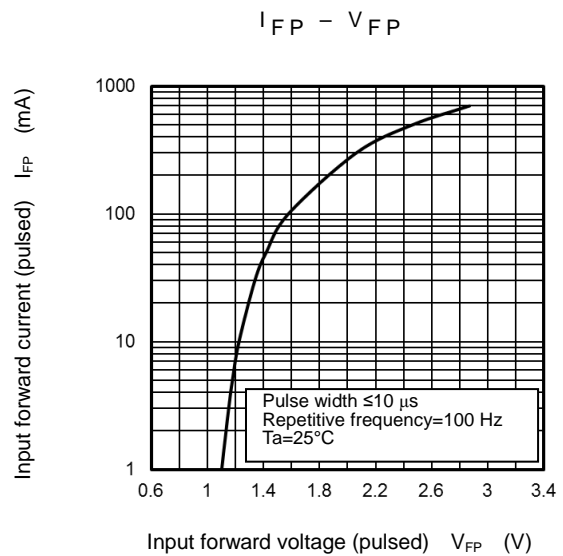
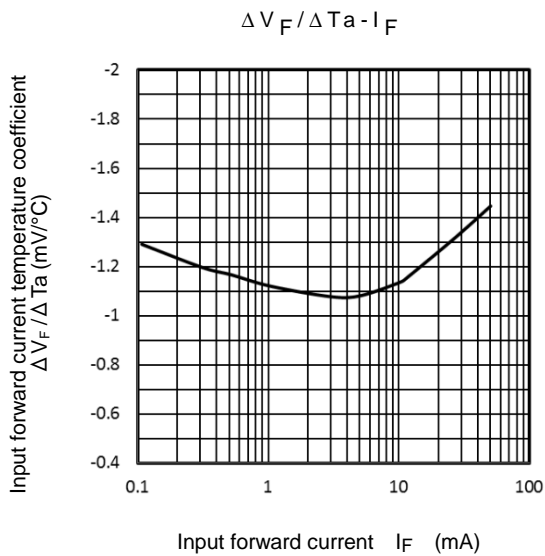
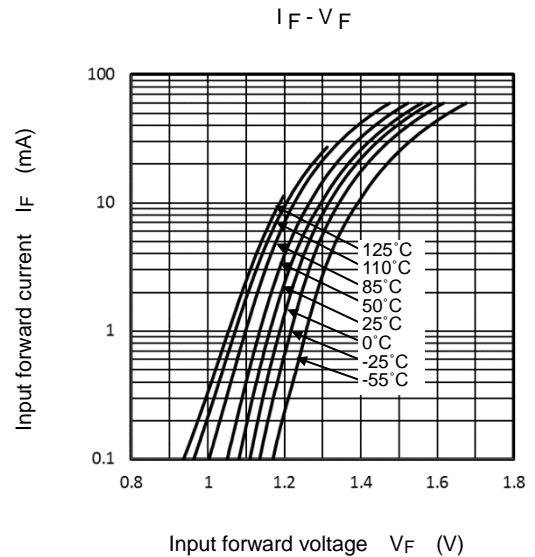
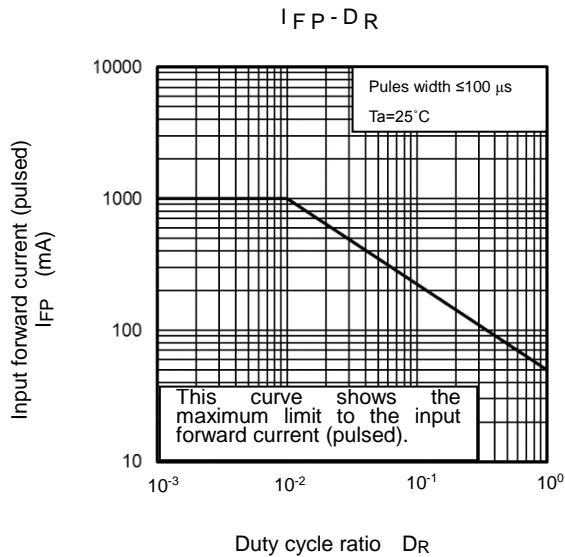
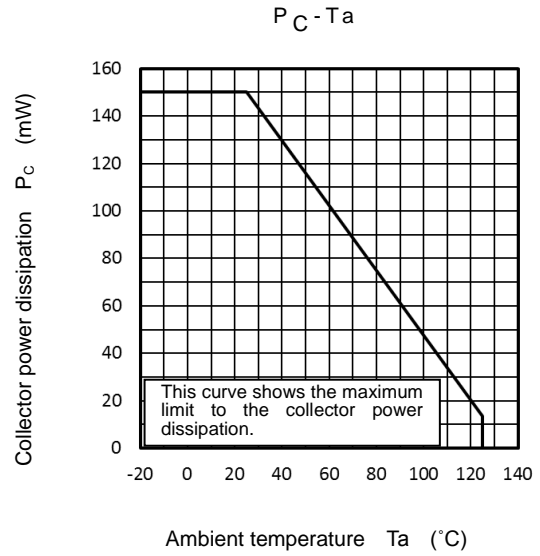
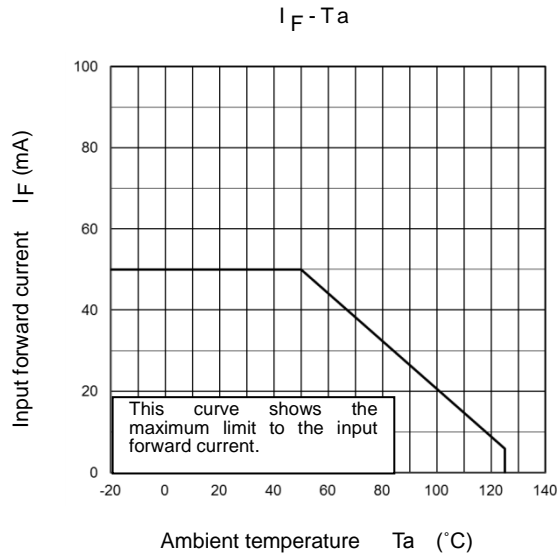
Switching Characteristics (Unless otherwise specified, Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Rise time	t _r	V _{CC} = 10 V, I _C = 2 mA R _L = 100 Ω	—	2	—	μs
Fall time	t _f		—	3	—	
Turn-on time	t _{on}		—	3	—	
Turn-off time	t _{off}		—	3	—	
Turn-on time	t _{on}	R _L = 1.9 kΩ (Figure 1) V _{CC} = 5 V, I _F = 16 mA	—	1.5	—	μs
Storage time	t _s		—	20	—	
Turn-off time	t _{off}		—	35	—	

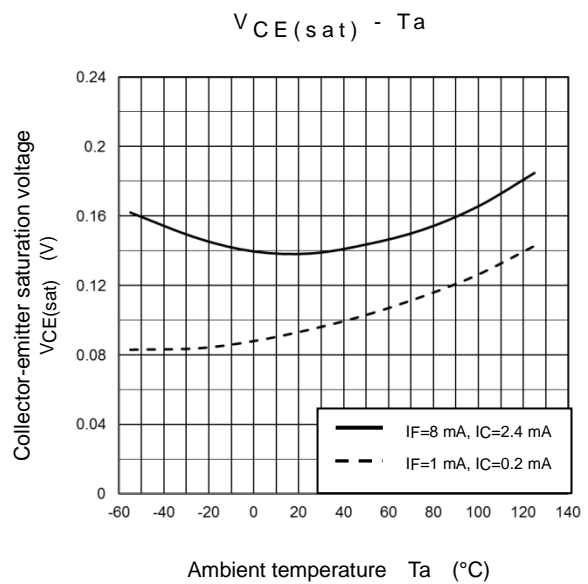
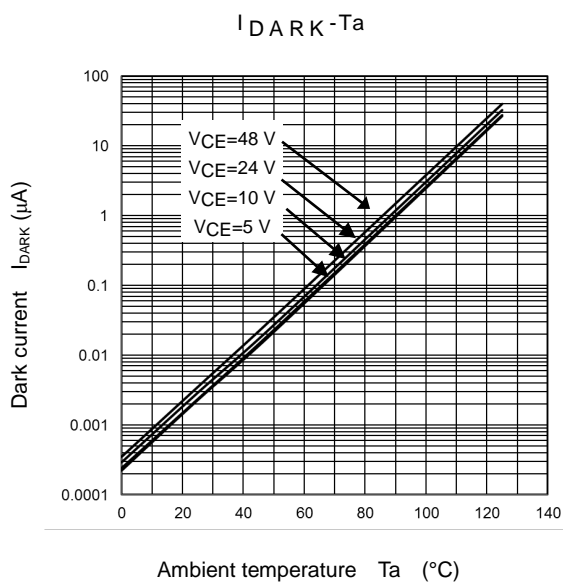
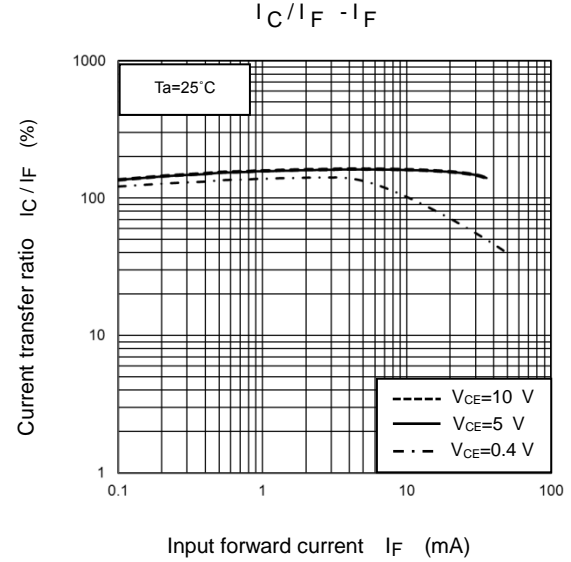
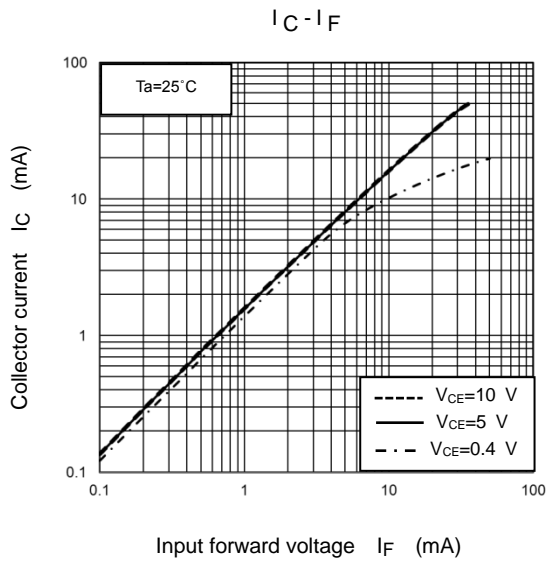
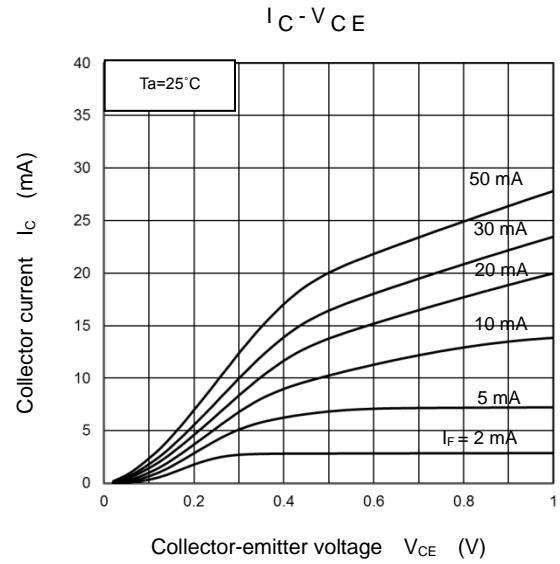
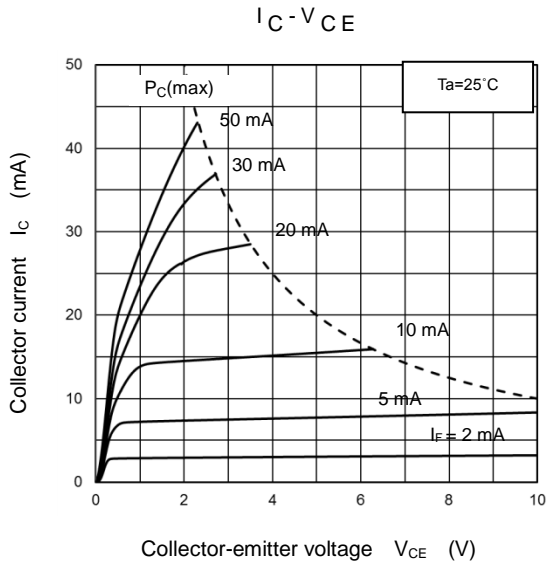
Figure 1: Switching Time Test Circuit



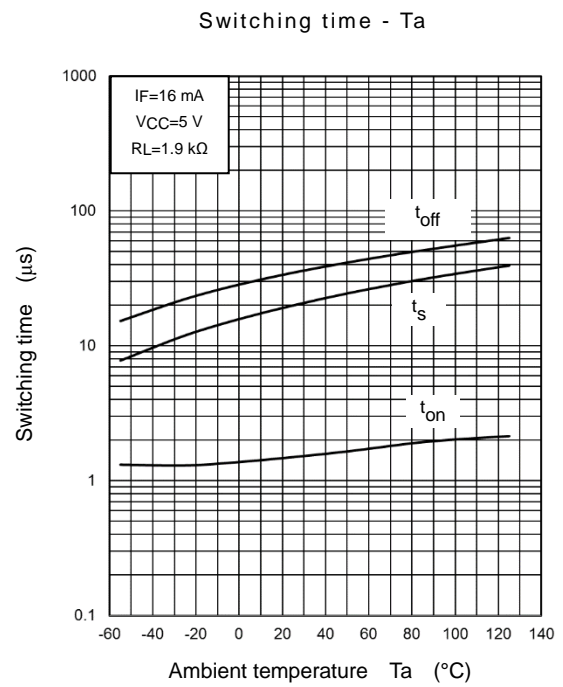
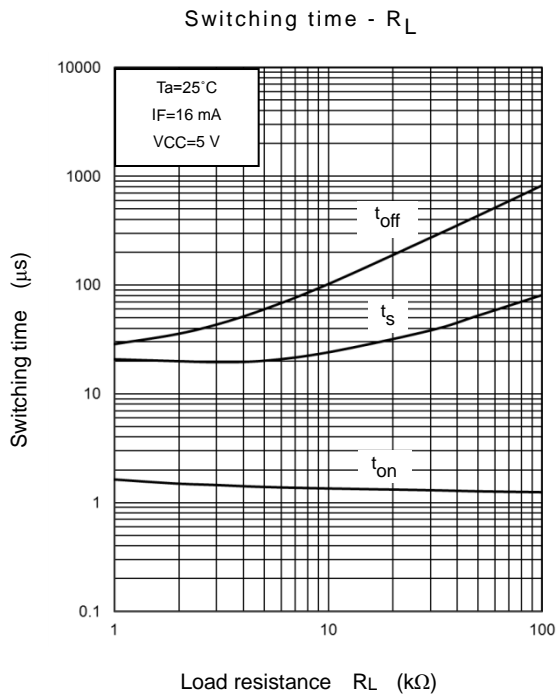
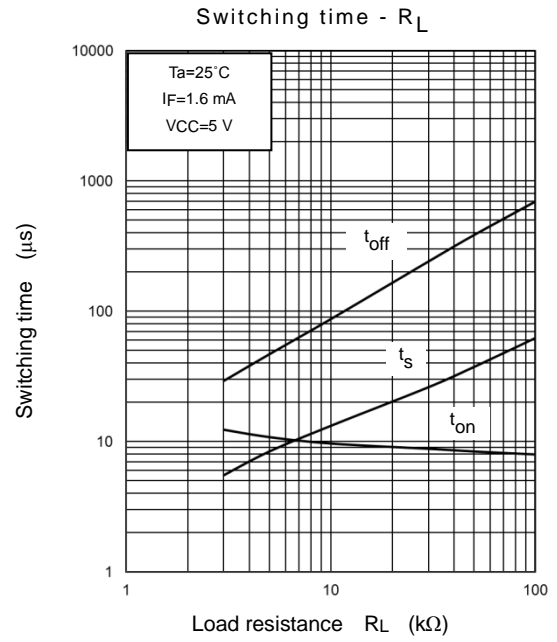
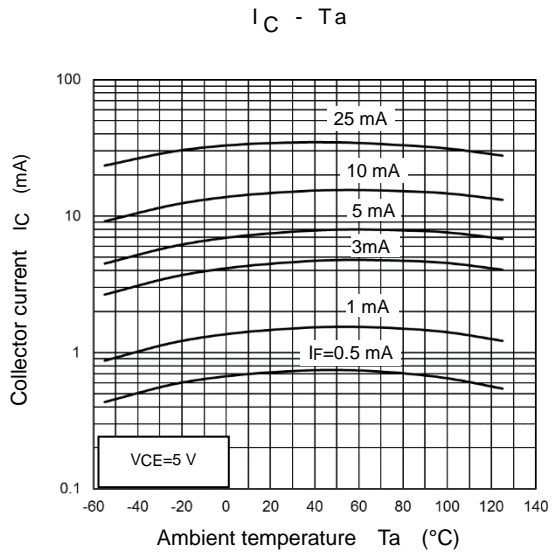
Characteristics Curves (Note)



NOTE: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



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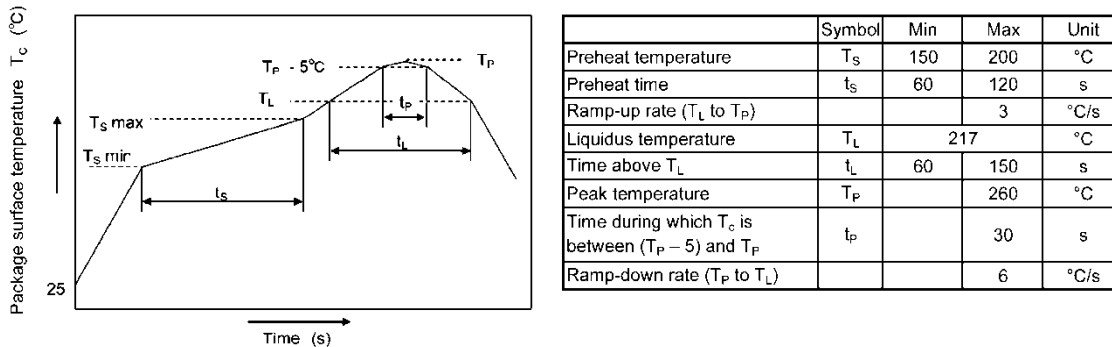
Soldering and Storage

1. Precautions for Soldering

The soldering temperature should be controlled as closely as possible to the conditions shown below, irrespective of whether a soldering iron or a reflow soldering method is used.

1) When Using Soldering Reflow

An example of a temperature profile when lead(Pb)-free solder is used



- The soldering temperature profile is based on the package surface temperature (See the figure shown below, which is based on the package surface temperature.)
- Reflow soldering must be performed once or twice.
- The mounting should be completed with the interval from the first to the last mountings being 2 weeks.

2) When using soldering Flow

- Preheat the device at a temperature of 150 °C (package surface temperature) for 60 to 120 seconds.
- Mounting condition of 260 °C within 10 seconds is recommended
- Flow soldering must be performed once.

3) When using soldering Iron

- Complete soldering within 10 seconds for lead temperature not exceeding 260 °C or within 3 seconds not exceeding 350 °C
- Heating by soldering iron must be done only once per lead.

2. Precautions for General Storage

- 1) Avoid storage locations where devices may be exposed to moisture or direct sunlight.
- 2) Follow the precautions printed on the packing label of the device for transportation and storage.
- 3) Keep the storage location temperature and humidity within a range of 5°C to 35°C and 45% to 75%, respectively.
- 4) Do not store the products in locations with poisonous gases (especially corrosive gases) or in dusty conditions.
- 5) Store the products in locations with minimal temperature fluctuations. Rapid temperature changes during storage can cause condensation, resulting in lead oxidation or corrosion, which will deteriorate the solderability of the leads.
- 6) When restoring devices after removal from their packing, use anti-static containers.
- 7) Do not allow loads to be applied directly to devices while they are in storage.
- 8) If devices have been stored for more than two years under normal storage conditions, it is recommended that you check the leads for ease of soldering prior to use.

Option: Specification for Embossed-Tape Packing (TP) for Mini-Flat Coupler

1. Applicable Package

Package Name	Product Type
SO16	Mini-Flat Coupler

2. Product Naming System

Type of package used for shipment is denoted by a symbol suffix after a product number. The method of classification is as below.

Example) TLP293-4(GB-TP,E

Part number: TLP293-4
 CTR rank: GB
 Tape type: TP
 [[G]]/RoHS COMPATIBLE: E (Note)

Note : Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 Jun 2011 on the restriction of the use of certain hazardous substances in electrical and electronics equipment.

3. Tape Dimensions Specification

3.1 Orientation of Device in Relation to Direction of Tape Movement

Device orientation in the recesses is as shown in Figure 3.1.1.

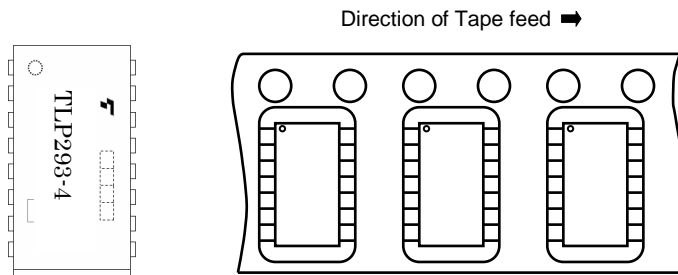


Figure3.1.1 Device Orientation

3.2 Packing Quantity

2000 pcs per reel

3.3 Empty Device Recesses are as Shown in Table 1.

Table 3.3.1 Empty Device Recesses

	Standard	Remarks
Occurrences of 2 or more successive empty device recesses	0 device	Within any given 40-mm section of tape, not including leader and trailer
Single empty device recesses	6 devices (max) per reel	Not including leader and trailer

3.4 Tape Leader and Trailer

The start end of the tape has 50 or more empty cavities. The hub end of the tape has 50 or more empty cavities and two empty turns only for a cover tape.

3.5 Tape Dimensions

Tape material: Synthetic Resin (protection against electrostatics)

Unit: mm

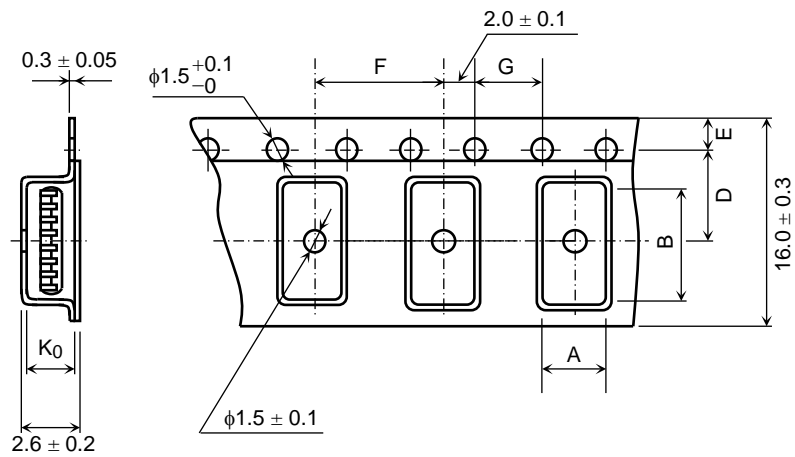


Figure 3.5.1 Tape Form

Table 3.5.1 Tape Dimensions

Unit: mm
Unless otherwise specified: ±0.1

Symbol	Dimension	Remark
A	7.5	—
B	10.5	—
D	7.5	Center line of indented square hole and sprocket hole
E	1.75	Distance between tape edge and hole center
F	12.0	Cumulative error +0.1/-0.3(max) per 10 feed holes
G	4.0	Cumulative error +0.1/-0.3(max) per 10 feed holes
K ₀	2.2	Internal space

3.6 Reel specification

Material: Synthetic Resin

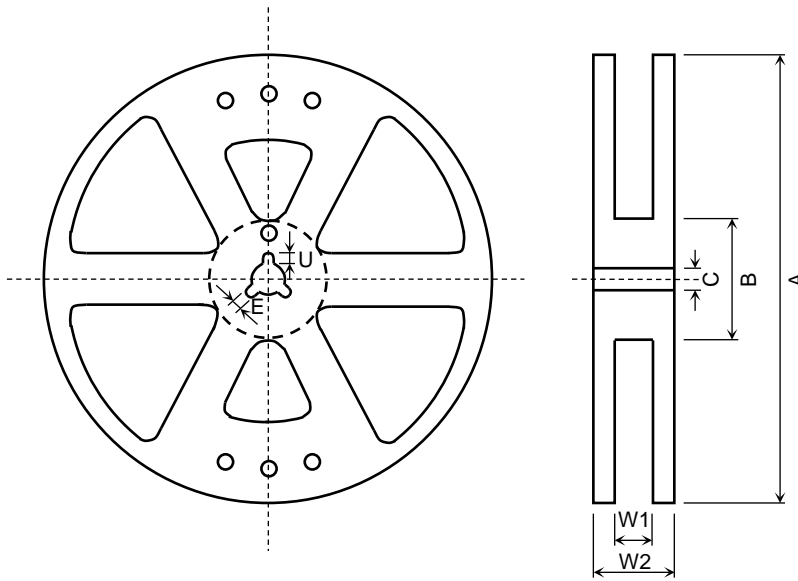


Figure 3.6.1 Reel Dimensions

Table 3.6.1 Reel Dimensions

Unit: mm

Symbol	Dimension
A	$\phi 330 \pm 2$
B	$\phi 80 \pm 1$
C	$\phi 13 \pm 0.5$
E	2.0 ± 0.5
U	4.0 ± 0.5
W1	17.5 ± 0.5
W2	21.5 ± 1.0

4. Packing

Packed in a shipping carton.

5. Label Format

The label on each carton and reel provides the part number, quantity, lot number, the Toshiba logo, CTR rank, etc.

6. Ordering Information

When placing an order, please specify the part number, CTR rank, tape type and quantity (must be a multiple of 2000) as shown in the following example.

Example) TLP293-4(GB-TP,E 2000 Pcs

Part number: TLP293-4
 CTR rank (GB
 Tape type: TP
 [[G]]/RoHS COMPATIBLE (Note)
 Quantity (must be a multiple of 2000)

Note : Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

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